

DECT RF / IF IC

Description

The U2761B is an integrated circuit manufactured in Atmel Wireless & Microcontrollers' UHFSS technology, designed for DECT application. It contains rejection mixer, IF amplifier, FM demodulator working at $f = f_{IF}/2$, baseband filter, RSSI, TX preamplifier and power-ramping generator for power amplifier.

Features

- Supply-voltage range 2.7 V to 4.7 V
- Low current consumption
- Few external components
- On-chip baseband filter
- LO switch and TX preamplifier
- Ramp-signal generator for power amplifier

Block Diagram

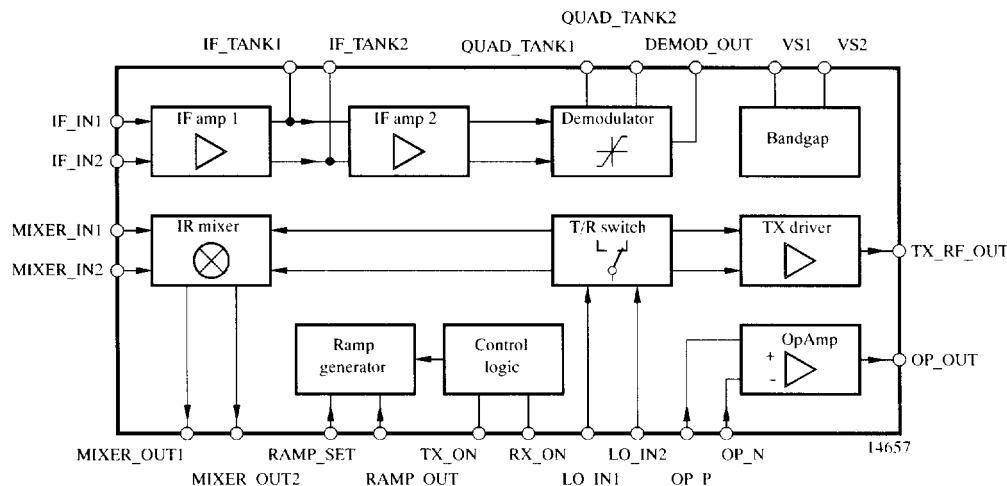


Figure 1. Block diagram

Ordering Information

Extended Type Number	Package	Remarks
U2761B-MFS	SSO28	Tube
U2761B-MFSG3	SSO28	Taped and reeled

Pin Description

Pin	Symbol	Function
1	RSSI	Received signal strength indicator output
2	PU	Hardware power-up input
3	IF_TANK1	IF tank circuit Pin 1
4	IF_TANK2	IF tank circuit Pin 2
5	GND1	Ground
6	MIXER_IN1	Mixer RF differential input 1
7	MIXER_IN2	Mixer RF differential input 2
8	GND2	Ground
9	TX_RF_OUT	Output of TX driver amplifier
10	VSI	Supply voltage input 1
11	IF_IN1	IF amplifier differential input 1
12	IF_IN2	IF amplifier differential input 2
13	RAMP_OUT	Ramp-signal output for PA
14	RAMP_SET	Slew-rate setting of ramp signal
15	RX_ON	RX control input
16	TX_ON	TX control input
17	MIXER_OUT1	Mixer IF differential output 1
18	MIXER_OUT2	Mixer IF differential output 2
19	VS2	Supply voltage input 2
20	LO_IN1	Local oscillator input 1
21	LO_IN2	Local oscillator input 2
22	GND3	Ground
23	QUAD_TANK1	Quadrature tank circuit 1
24	QUAD_TANK2	Quadrature tank circuit 2
25	DEMOD_OUT	Output of demodulator
26	OP_N	OP - Input inverting
27	OP_P	OP - Input non-inverting
28	OP_OUT	OP - Output

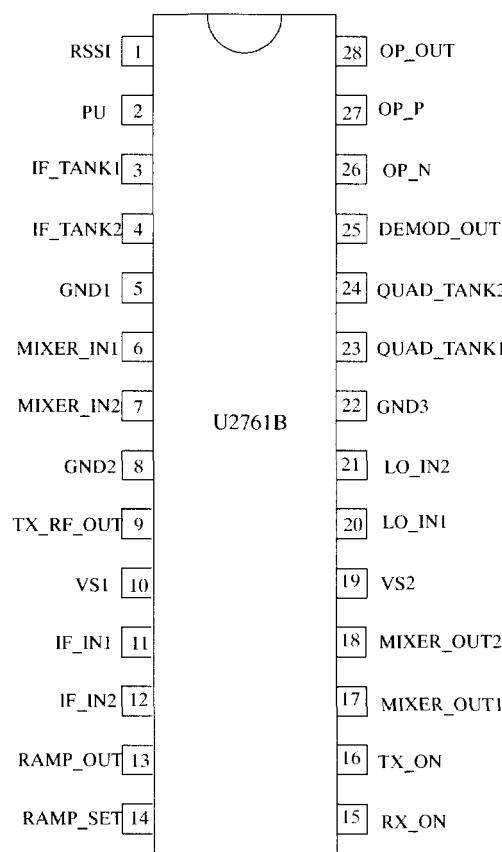


Figure 2. Pinning

Absolute Maximum Ratings

All voltages refer to GND (Pins 5, 8 and 22)

Parameter	Symbol	Value	Unit
Supply voltage	V _S	5.0	V
Junction temperature	T _j	150	°C
Storage temperature	T _{stg}	-40 to +125	°C



Thermal Resistance

Parameter	Symbol	Value	Unit
Junction ambient	R _{thJA}	130	K/W

Operating Range

All voltages refer to GND (Pins 5, 8 and 22)

Parameter	Symbol	Min.	Typ.	Max.	Unit
Supply voltage	V _S	2.7	3.0	4.7	V
Ambient temperature	T _{amb}	-25	+25	+85	°C

Electrical Characteristics

Test conditions: V_S = 3.0 V, T_{amb} = 25°C, unless otherwise specified

Parameter	Test Conditions / Pins	Symbol	Min.	Typ.	Max.	Unit
Power supply						
Total supply current	TX	I _S		30		mA
	RX			50		mA
	RX (RSSI only)			47		mA
	Standby, PU = GND		1	10		µA
IR mixer Pins 6, 7, 17 and 18						
Image-rejection ratio	Pins 17 and 18	IRR		20		dB
DSB noise figure	Pins 17 and 18	NFDSB= NFSSB		10		dB
Conversion gain	R _{load} = 200 Ω	G _{conv}		12		dB
Output interception point	Pins 17 and 18	OIP3		10		dBm
Input impedance	Pins 6 and 7	Z _{in}		50		Ω
Input matching	Pins 6 and 7	VSWR _{in}		<2:1		
LO switch and TX driver Pin 9, 20 and 21						
Power gain (high)	@ P _{in} = -40 dBm	G _p		30		dB
Input impedance	Pin 20 or Pin 21 to GND	Z _{in}		50		Ω
Input matching	Pins 20 and 21	VSWR _{in}		<2:1		
Isolation LO-TX	RX mode: LO Pin 20 or Pin 21 to Pin 9	Isol		37		dB

Electrical Characteristics (continued)

Test conditions: $V_S = 3.0$ V, $T_{amb} = 25^\circ\text{C}$, unless otherwise specified

Parameter	Test Conditions / Pins	Symbol	Min.	Typ.	Max.	Unit
Output impedance	Pin 9	Z_{out}		100		Ω
Maximum output power	Pin 9	P_{max}		3		dBm
Gain compression	@ TX_RF_OUT	P_{1dB}		1		dBm
Output interception point	Pin 9	OIP3		10		dBm
IF amplifier	Pins 3, 4, 11 and 12					
Input impedance	Pins 11 and 12	Z_{in}	200		400	Ω
Lower cut-off frequency		f_{l3dB}		90		MHz
Upper cut-off frequency		f_{u3dB}		130		MHz
Power gain		G_p		85		dB
Bandwidth of external tank circuit	Pins 3 and 4	BW_{3dB}		10		MHz
Noise figure		NF		9		dB
RSSI	Pins 1, 6 and 7					
RSSI sensitivity	At IF_IN1, IF_IN2, Pins 6 and 7	P_{min}		20		$\text{dB}\mu\text{V}$
RSSI compression	At IF_IN1, IF_IN2, Pins 6 and 7	P_{max}		100		$\text{dB}\mu\text{V}$
RSSI dynamic range		DR		80		dB
RSSI resolution	Slope of the RSSI has to be steady	Acc		± 2		dB
RSSI rise time	$P_{in} = 30 \text{ dB}\mu\text{V}$ to $100 \text{ dB}\mu\text{V}$, Pin 1	t_r		1		μs
RSSI fall time	$P_{in} = 100 \text{ dB}\mu\text{V}$ to $30 \text{ dB}\mu\text{V}$, Pin 1	t_f		1		μs
Quiescent output current	@ $P_{in} < 20 \text{ dB}\mu\text{V}$ at IF_IN1, IF_IN2 Pin 1	I_{out}		30		μA
Max. output current	@ $P_{in} = 100 \text{ dB}\mu\text{V}$ at IF_IN1, IF_IN2 Pin 1	I_{out}		150		μA
FM demodulator	Pins 23, 24 and 25					
Co-channel rejection ratio	@ $P_{in} = -75 \text{ dBm}$ at IR-mixer input	CCRR		10		dB
Sensitivity	Quality factor of external tank circuit approx. 20, $f_{res} = f_{IF}/2$	S		0.5		V/MHz
Amplitude of recovered signal	Nominal deviation of signal $\pm 288 \text{ kHz}$	A		288		mVss
Output-voltage DC range	Pin 25	F _{MoutDC}	0.4		$V_S - 0.4$	V
Output impedance	Pin 25	Z_{out}		13		$k\Omega$
AM rejection ratio	Pin 25	AMRR		tbd		dB
OpAmp	Pins 26, 27 and 28					
Power gain bandwidth		PGBW		10		MHz
Excess phase	$R_{load} = 1 \text{ k}\Omega$, $C_{load} = 15 \text{ pF}$	d		80		$^\circ$
Input offset voltage	Pins 26 and 27	V_{offs}		± 1		mV
Open-loop gain		g		70		dB

Electrical Characteristics (continued)

Test conditions: $V_S = 3.0 \text{ V}$, $T_{\text{amb}} = 25^\circ\text{C}$, unless otherwise specified

Parameter	Test Conditions / Pins	Symbol	Min.	Typ.	Max.	Unit
Output-voltage range	Pin 28	V_{out}	0.3		$V_S - 0.3$	V
Common mode input voltage	Pins 26 and 27	V_{in}	0.3		$V_S - 0.3$	V
Common mode rejection ratio	Pin 28	CMRR		t.b.d.		dB
Total harmonic distortion	Pin 28	THD		t.b.d.		%
Ramp generator						
Pins 13 and 14						
Min. output voltage	Accord. to PA RAMP input	V_{min}		0.2		V
Max. output voltage	Accord. to PA RAMP input	V_{max}		1.95		V
Rise time	$C_{\text{RAMP}} = 270 \text{ pF}$ at Pin 14	t_r		5		µs
Fall time	$C_{\text{RAMP}} = 270 \text{ pF}$ at Pin 14	t_f		5		µs
Logic input levels (RX_ON, TX_ON) Pins 15 and 16						
High input level	= '1'	V_{iH}	1.5			V
Low input level	= '0'	V_{iL}			0.5	V
High input current	= '1'	I_{iH}	-5		5	µA
Low input current	= '0'	I_{iL}	-5		5	µA
Power / standby						
Power-up high input level		V_{PU}	2.0			V
Standby low input level		$V_{PU,\text{OFF}}$			0.7	V
Power-up high input current		I_{PU}	20 40	30 60	40 80	µA
Standby low input current		$I_{PU,\text{OFF}}$			0.1 1	µA
Settling time $VS = 0 \rightarrow$ active operation		t_{soa}		< 10		µs
Settling time standby \rightarrow active operation		t_{ssa}		< 10		µs
Settling time active operation \rightarrow standby		t_{sas}		< 2		µs

Active Blocks Corresponding to RX / TX

	Logic			Active Parts								
	PU	RX_ON	TX_ON	OP	Demo-dulator	IF amplifiers	IR mixer	RSSI	RX switch	TX switch	TX driver	Ramp generator
TX mode	1	0	1	off	off	off	off	off	off	on	on	on
RX mode	1	1	0	on	on	on	on	on	on	off	off	off
RSSI	1	1	1	off	off	on	on	on	on	off	off	off
Standby	0	X	X	off	off	off	off	off	off	off	off	off
	1	0	0	off	off	off	off	off	off	on	off	off

Typical Application Circuit

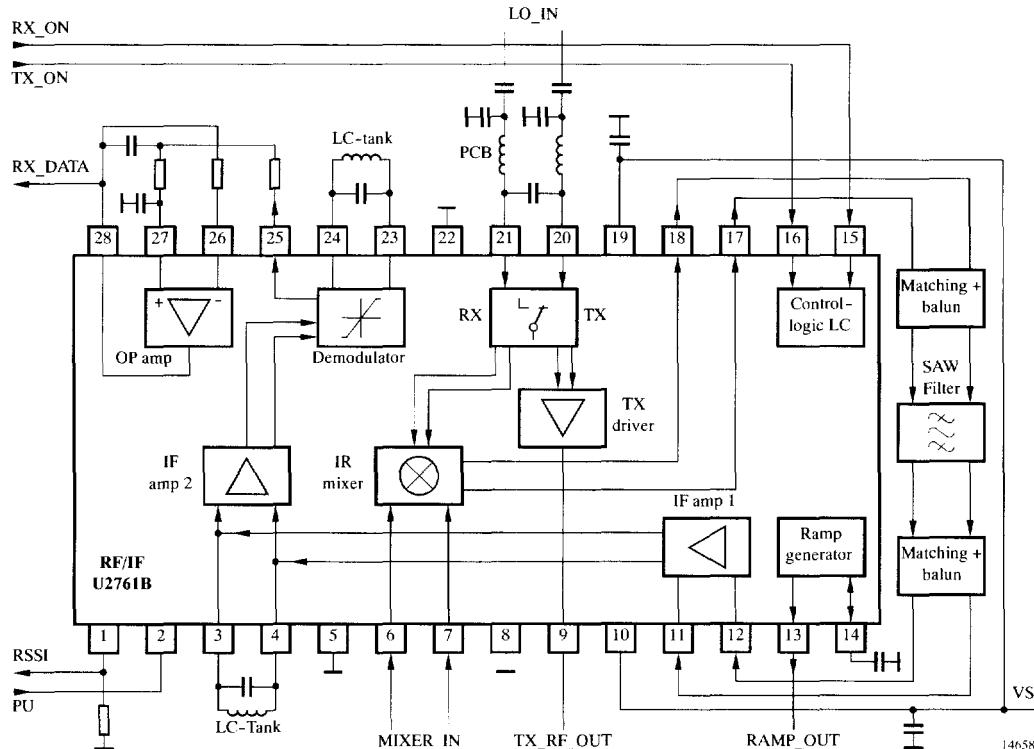


Figure 3. Typical application circuit

Recommended Baseband Filter ($f_{3dB} \approx 570$ kHz)

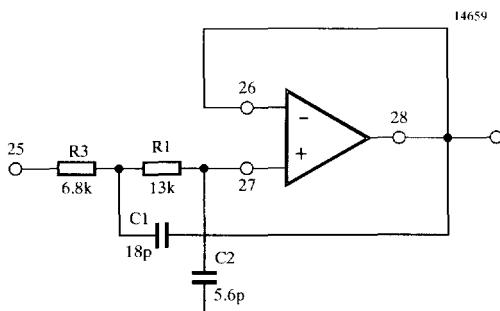


Figure 4. Recommended baseband filter

Input / Output Interface Circuits

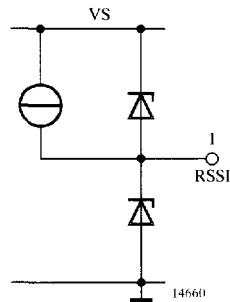


Figure 5.

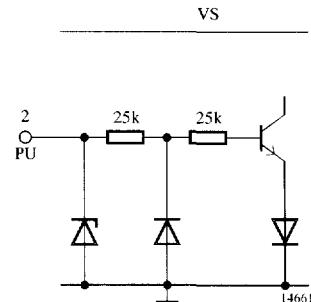


Figure 8.

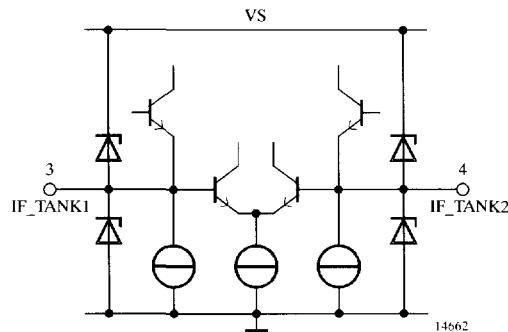


Figure 6.

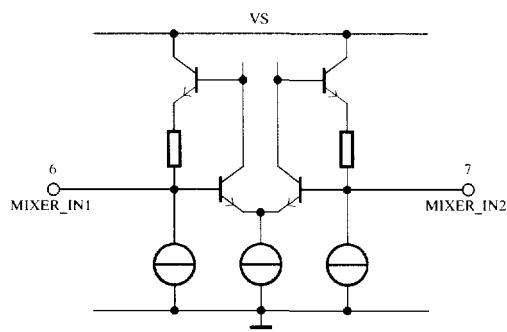


Figure 9.

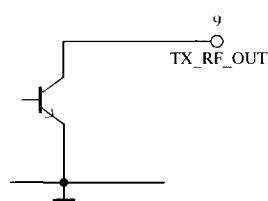


Figure 7.

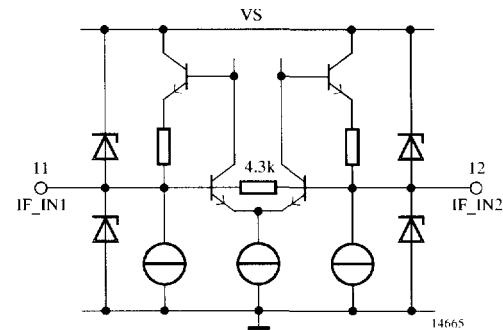


Figure 10.

Input / Output Interface Circuits (continued)

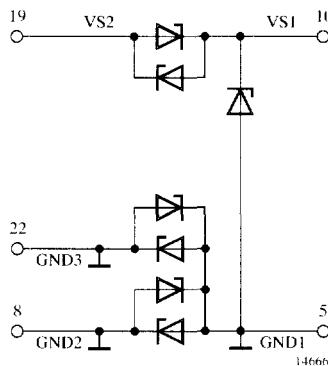


Figure 11.

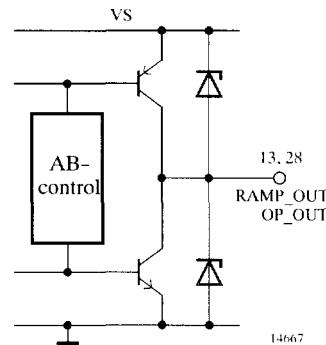


Figure 14.

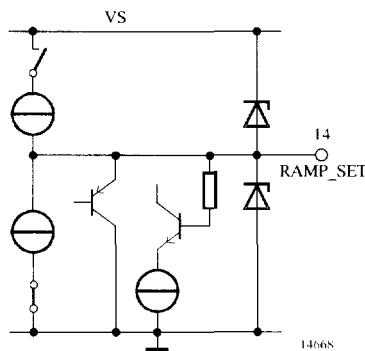


Figure 12.

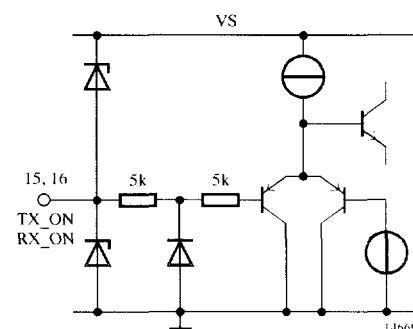


Figure 15.

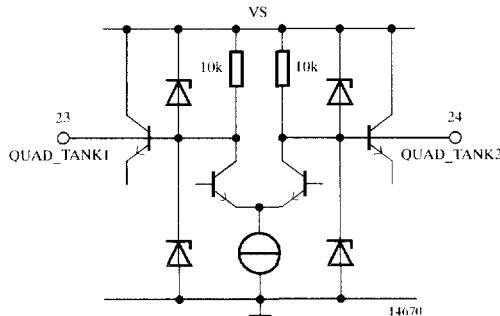


Figure 13.

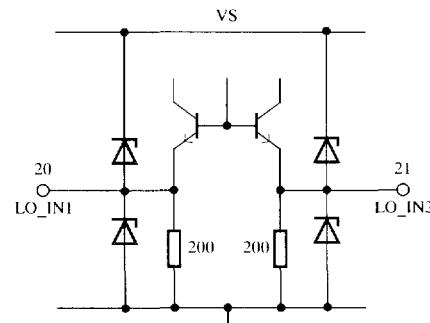


Figure 16.

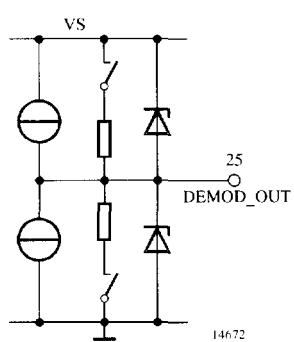
Input / Output Interface Circuits (continued)


Figure 17.

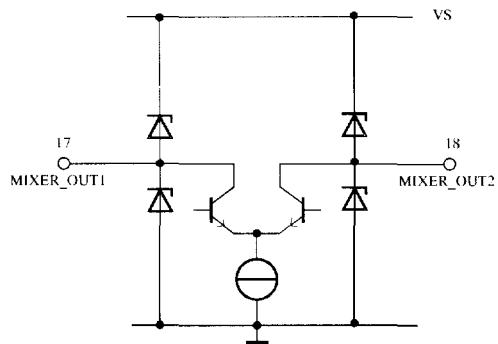


Figure 19.

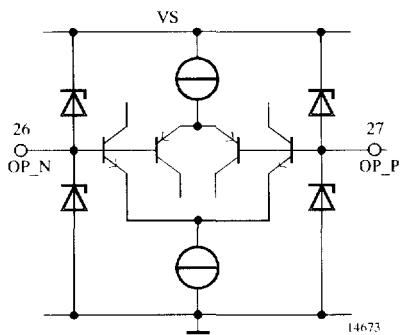
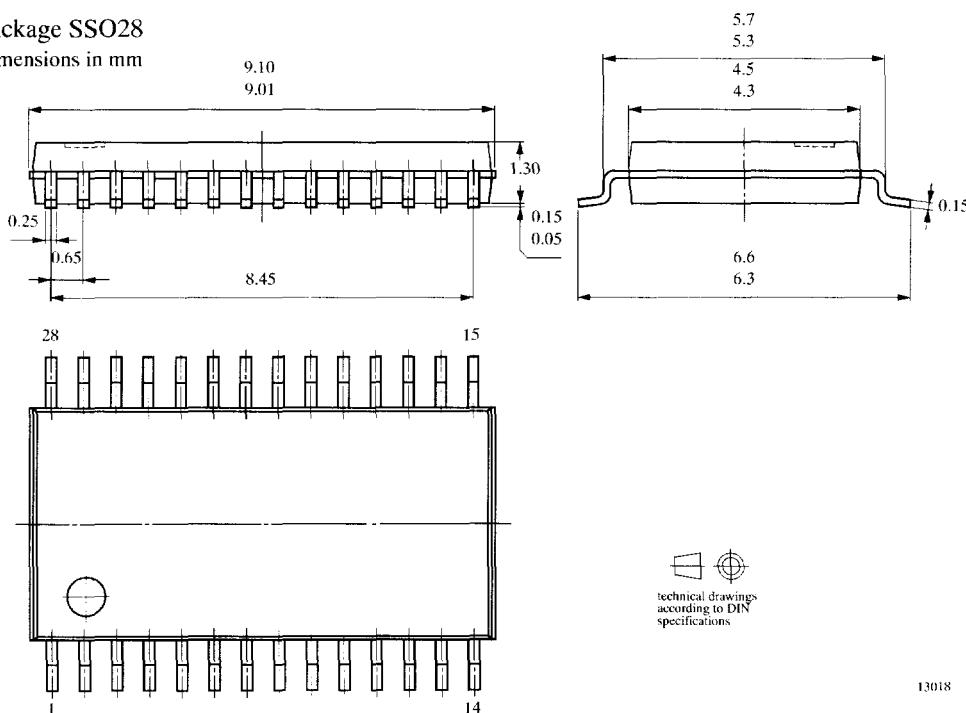


Figure 18.

Package Information

Package SSO28

Dimensions in mm



13018